

## InAsSb photovoltaic detectors

P13243 series

# High-speed response and high sensitivity in the spectral band up to 5 $\mu$ m, non-cooled type infrared detectors

The P13243 series are photovoltaic type infrared detectors that have achieved high sensitivity in the spectral band up to 5  $\mu$ m without cooling using Hamamatsu unique crystal growth technology and process technology. Because it is non-cooled, it is compact and easy to handle.

### Features

### Applications

- High sensitivity
- High-speed response
- High shunt resistance
- Non-cooled, small package

- Gas detection (CH4, CO2, CO, etc.)
- Radiation thermometers

### Structure

Parameter	P13243-011CA	P13243-011MA	Unit
Window material	Anti-reflective coating Si		
Package	Ceramic	TO-46	-
Cooling	Non-cooled		
Photosensitive area	0.7 × 0.7		
Field of view (FOV)	55	82	degrees

### Absolute maximum ratings

Parameter	Symbol	Condition	P13243-011CA	P13243-011MA	Unit
Reverse voltage	Vr		1		V
Operating temperature	Topr	No dew condensation*1	-40 to +85		°C
Storage temperature	Tstg	No dew condensation*1	-40 to +85		°C
Soldering conditions			Peak temperature 240 °C max.	Up to 260 °C, up to 10 s	-

\*1: When there is a temperature difference between a product and the surrounding area in high humidity environment, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

1

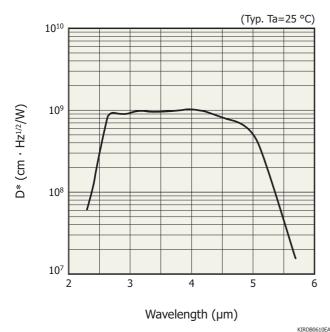
### Electrical and optical characteristics (Ta=25 °C)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Peak sensitivity wavelength	λр		-	3.5	-	μm
Cutoff wavelength	λс		5.0	5.3	-	μm
Photosensitivity	S	$\lambda = \lambda p^{*2}$	4.0	4.5	-	mA/W
Shunt resistance	Rsh	VR=10 mV	120	300	-	kΩ
Detectivity	D*	(λρ, 600, 1)	$8.0 \times 10^{8}$	$1.0 \times 10^{9}$	-	cm·Hz <sup>1/2</sup> /W
Noise equivalent power	NEP	$\lambda = \lambda p^{*2}$	-	7.0 × 10 <sup>-11</sup>	$8.8 \times 10^{-11}$	W/Hz <sup>1/2</sup>
Rise time	tr	10 to 90%, without light input window, $\lambda$ =1.55 µm	-	6	12	ns

\*2: Uniform irradiation on the entire photosensitive area

Note: Uniform irradiation must be applied to the entire photosensitive area during use.

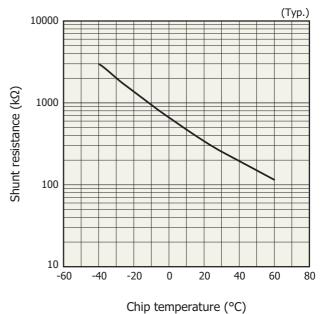
### Spectral response (D\*)





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### Shunt resistance vs. chip temperature

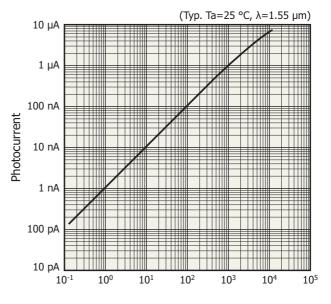


KIRDB0611EB

### Linearity

50

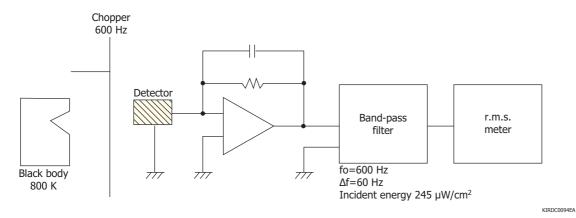
PHOTON IS OUR BUSINESS



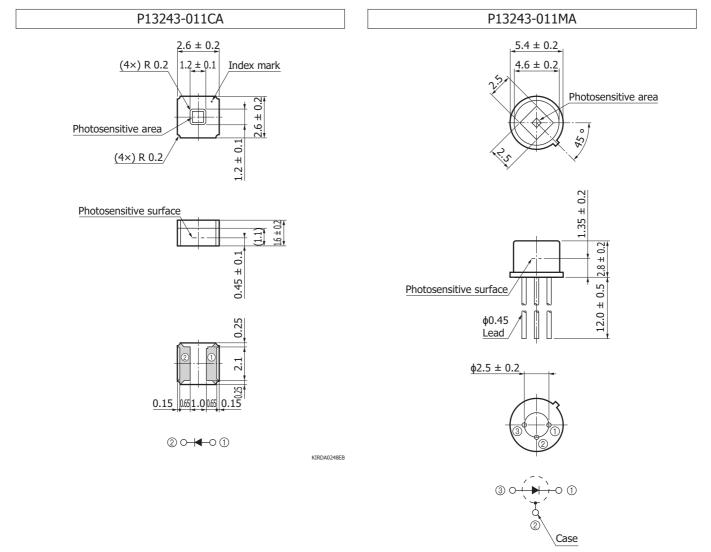
Incident light level (µW)

KIRDB0615EA

### Measurement circuit example

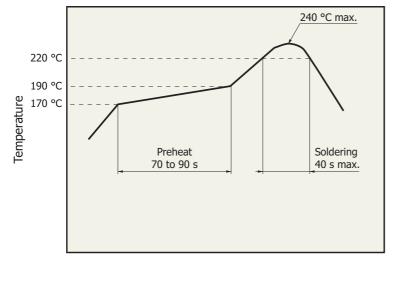


### Dimensional outlines (unit: mm)



KIRDA0249EB





### Recommended temperature profile for reflow soldering (P13243 series)

Time

KIRDB0616EA

The effect that the product is subject to during reflow soldering varies depending on the circuit board and reflow furnace that are used. Before actual reflow soldering, check for any problems by testing out the reflow soldering methods in advance.

### Related information

www.hamamatsu.com/sp/ssd/doc\_en.html

- Precautions
- Disclaimer
- Technical information
- · Infrared detectors

Information described in this material is current as of January 2017.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

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